

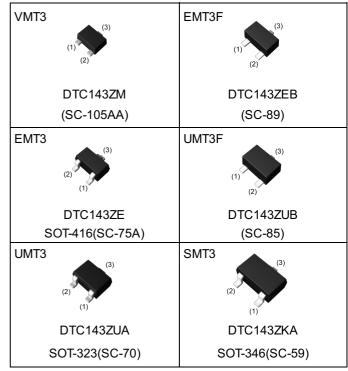
NPN 100mA 50V Digital Transistors (Bias Resistor Built-in Transistors)

Parameter	Value
V _{CC}	50V
I _{C(MAX.)}	100mA
R ₁	4.7kΩ
R_2	47kΩ

Features

- 1) Built-in bias resistors $.R_1 = 4.7k\Omega, R_2 = 47k\Omega.$
- 2) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see inner circuit).
- 3) Only the on/off conditions need to be set for operation, making the circuit design easy.
- 4) Complementary PNP Types: DTA143Z series

Outline

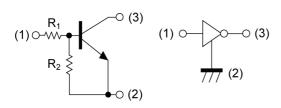


Application

INVERTER, INTERFACE, DRIVER

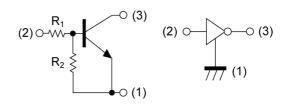
Inner circuit

DTC143ZM/ DTC143ZEB/ DTC143ZUB



- (1) IN (BASE)
- (2) GND (EMITTER)
- (3) OUT (COLLECTOR)

DTC143ZE/ DTC143ZUA/ DTC143ZKA



- (1) GND (EMITTER)
- (2) IN (BASE)
- (3) OUT (COLLECTOR)

Packaging specifications

Part No.	Package	Package size	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit.(pcs)	Marking
DTC143ZM	VMT3	1212	T2L	180	8	8000	E23
DTC143ZEB	EMT3F	1616	TL	180	8	3000	E23
DTC143ZE	EMT3	1616	TL	180	8	3000	E23
DTC143ZUB	UMT3F	2021	TL	180	8	3000	123
DTC143ZUA	UMT3	2021	T106	180	8	3000	123
DTC143ZKA	SMT3	2928	T146	180	8	3000	E23

● **Absolute maximum ratings** (T_a = 25°C)

Pa	rameter	Symbol	Values	Unit
Supply voltage	Supply voltage			V
Input voltage	V _{IN}	-5 to 30	V	
Output current	Io	100	mA	
Collector current			100	mA
	DTC143ZM		150	
	DTC143ZEB		150	mW
Davis a disaination	DTC143ZE	P _D *2	150	
Power dissipation	DTC143ZUB	P _D '	200	
	DTC143ZUA		200	=
DTC143ZKA			200	
Junction temperature		T _j	150	°C
Range of storage temperate	ure	T _{stg}	-55 to +150	°C

• Electrical characteristics $(T_a = 25^{\circ}C)$

Parameter	Symbol	Conditions	Values			Unit
- Farameter	Conditions		Min.	Тур.	Max.	Offic
Input voltage	$V_{l(off)}$	$V_{CC} = 5V, I_{O} = 100 \mu A$	-	-	0.5	V
Input voltage	V _{I(on)}	$V_{O} = 0.3V, I_{O} = 5mA$	1.3	-	-	V
Output voltage	V _{O(on)}	$I_{O}/I_{I} = 5mA/0.25mA$	1	100	300	mV
Input current	I _I	V _I = 5V	1	-	1.8	mA
Output current	I _{O(off)}	$V_{CC} = 50V, V_{I} = 0V$	1	-	500	nA
DC current gain	G _I	V _O = 5V, I _O = 10mA	80	-	-	-
Input resistance	R ₁	-	3.29	4.7	6.11	kΩ
Resistance ratio	R ₂ /R ₁	-	8	10	12	-
Transition frequency	f _T *1	$V_{CE} = 10V, I_{E} = -5mA,$ f = 100MHz	-	250	-	MHz

^{*1} Characteristics of built-in transistor

^{*2} Each terminal mounted on a reference land

● Electrical characteristic curves (T_a =25°C)

Fig.1 Input voltage vs. output current (ON characteristics)

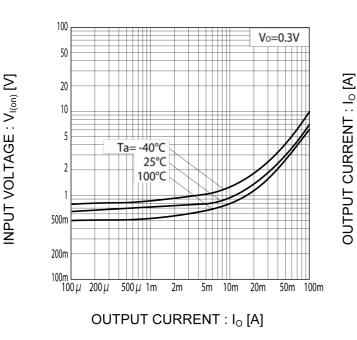
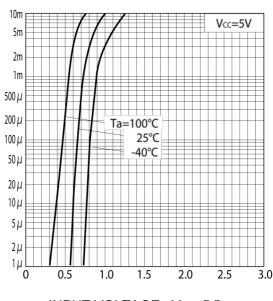


Fig.2 Output current vs. input voltage (OFF characteristics)



INPUT VOLTAGE : $V_{I(off)}[V]$

Fig.3 Output current vs. output voltage

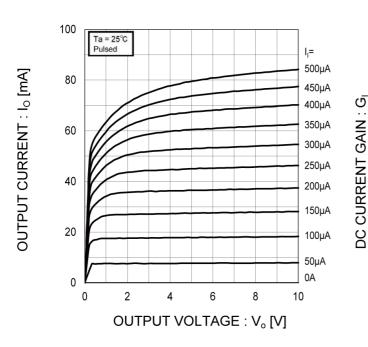
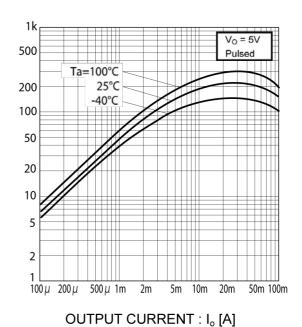
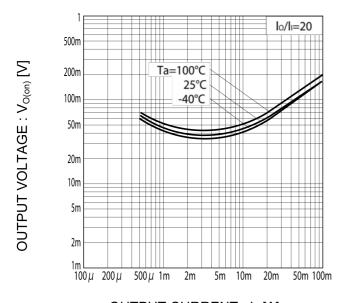


Fig.4 DC current gain vs. output current



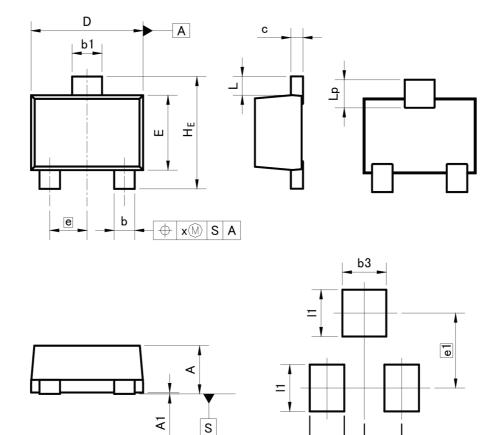
●Electrical characteristic curves (T_a =25°C)

Fig.5 Output voltage vs. output current



OUTPUT CURRENT : I_o [A]

VMT3



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

b2

DIM -	MILIM	ETERS	INC	HES
DIM [MIN	MAX	MIN	MAX
Α	0.45	0.55	0.018	0.022
A1	0.00	0.10	0.000	0.004
b	0.17	0.27	0.007	0.011
b1	0.27	0.37	0.011	0.015
С	0.08	0.18	0.003	0.007
D	1.10	1.30	0.043	0.051
E	0.70	0.90	0.028	0.035
е	0.4	40	0.02	
HE	1.10	1.30	0.043	0.051
L	0.10	0.30	0.004	0.012
Lp	0.20	0.40	0.008	0.016
х		0.10	_	0.004
DIM	MILIM	ETERS	INCI	HES
DIM	MIN	MAX	MIN	MAX
b2		0.37	-	0.015
b3	_	0.47	-	0.019

Dimension in mm/inches

e1

11

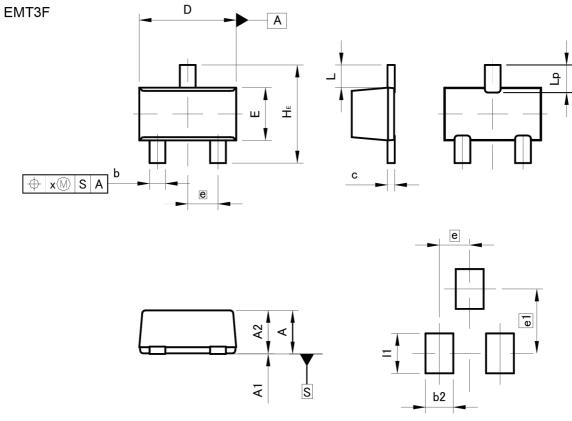


0.020

0.031

0.50

0.80



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

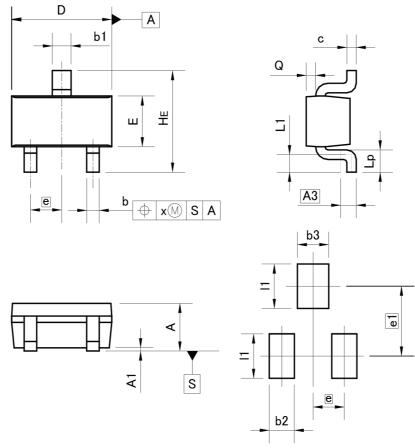
DIM	MILIM	ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	0.65	0.85	0.026	0.033
A1	0.00	0.10	0.000	0.004
A2	0.60	0.80	0.024	0.031
b	0.21	0.36	0.008	0.014
С	0.08	0.18	0.003	0.007
D	1.50	1.70	0.059	0.067
E	0.76	0.96	0.030	0.038
е	0.50		0.0	20
HE	1.50	1.70	0.059	0.067
L	0.0	37	0.0	15
Lp	0.35	0.55	0.014	0.022
х	_	0.10		0.004

DIM	MILIMETERS		INCHES	
	MIN	MAX	MIN	MAX
b2	_	0.46	_	0.018
e1	-	1.05	-	0.041
11	=	0.65	. —	0.026

Dimension in mm/inches



EMT3



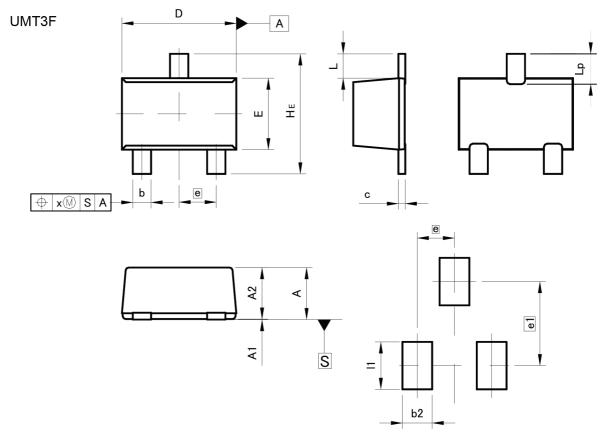
Pattern of terminal position areas [Not a recommended pattern of soldering pads]

DIM -	MILIM	ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	0.60	0.80	0.024	0.031
A1	0.00	0.10	0.000	0.004
A3	0.3	25	0.0	10
b	0.15	0.30	0.006	0.012
b1	0.25	0.40	0.010	0.016
С	0.10	0.20	0.004	0.008
D	1.50	1.70	0.059	0.067
E	0.70	0.90	0.028	0.035
е	0.9	50	0.0	20
HE	1.40	1.80	0.055	0.071
L1	0.10	-	0.004	-
Lp	0.15		0.006	-
Q	0.05	0.25	0.002	0.010
x		0.10		0.004

DIM	MILIM	ETERS	INCHES	
DIM	MIN	MAX	MIN	MAX
b2	-	0.40		0.016
b3	-	0.50	-	0.020
e1	1.	10	0.0	043
11	43	0.70		0.028

Dimension in mm/inches





Pattern of terminal position areas [Not a recommended pattern of soldering pads]

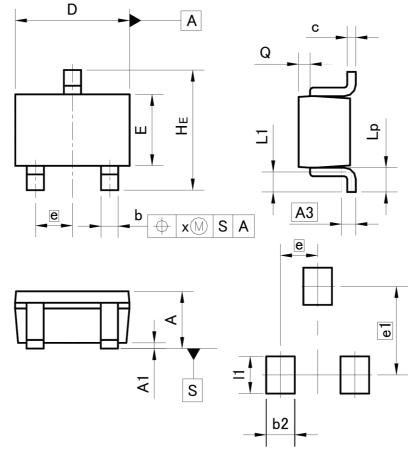
DIM	MILIME	ETERS	INCHES	
DIM	MIN	MAX	MIN	MAX
Α	0.85	1.05	0.033	0.041
A1	0.00	0.10	0.000	0.004
A2	0.80	1.00	0.031	0.039
b	0.27	0.42	0.011	0.017
С	0.08	0.18	0.003	0.007
D	1.90	2.10	0.075	0.083
E	1.15	1.35	0.045	0.053
е	0.0	0.65		26
HE	2.00	2.20	0.079	0.087
L	0.4	43	0.0	17
Lp	0.43	0.63	0.017	0.025
х	_	0.10	_	0.004

DIM	MILIME	ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
b2	_	0.52	_	0.020
e1	1.	47	0.0	058
11	=	0.83	-	0.033

Dimension in mm/inches



UMT3



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

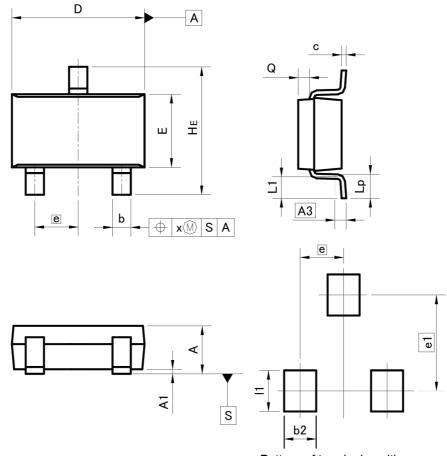
DIM	MILIM	ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	0.80	1.00	0.031	0.039
A1	0.00	0.10	0.000	0.004
A3	0.	25	0.0	10
b	0.15	0.30	0.006	0.012
С	0.10	0.20	0.004	0.008
D	1.90	2.10	0.075	0.083
E	1.15	1.35	0.045	0.053
е	e 0.65 0.026		26	
HE	2.00	2.20	0.079	0.087
L1	0.20	0.50	0.008	0.020
Lp	0.25	0.55	0.010	0.022
Q	0.10	0.30	0.004	0.012
х	-	0.10	-	0.004

DIM	MILIMETERS		INCHES	
DIM	MIN	MAX	MIN -	MAX
b2	-	0.50	_	0.020
e1	1.55		0.061	
11	-	0.65	_	0.026

Dimension in mm/inches



SMT3



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

DIM	MILIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	1.00	1.30	0.039	0.051
A1	0.00	0.10	0.000	0.004
A3	0.25		0.010	
b	0.35	0.50	0.014	0.020
С	0.09	0.25	0.004	0.010
D	2.80	3.00	0.110	0.118
E	1.50	1.80	0.059	0.071
е	0.95		0.037	
HE	2.60	3.00	0.102	0.118
L1	0.30	0.60	0.012	0.024
Lp	0.40	0.70	0.016	0.028
Q	0.20	0.30	0.008	0.012
х	-	0.10	_	0.004
У	_	0.10	_	0.004
	MILIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
h2	1000	0.60	1000	0.004

DIM	MILIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
b2	44	0.60	_	0.024
e1	2.10		0.083	
- 11	-	0.90	-	0.035

Dimension in mm/inches



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